

BEAM LOADING EFFECTS IN SSRF STORAGE RING

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Abstract

The beam current in the storage ring of Shanghai Synchrotron Radiation Facility (SSRF) is now normally 240 mA and projected to be raised to 300 mA. Heavy beam loading will be serious and associated Robinson instability needs to be compressed. In this paper, the beam loading effects in SSRF storage ring and methods to increase current limit will be discussed.

INTRODUCTION

The upgrade project of SSRF is under design and the storage ring beam current is aimed to be raised from 240 mA to 300 mA. With the help of long time high power conditioning and the accurate control of low level RF(LLRF) system, long term stability of beam current have been reached with the total RF cavity voltage at 4.8 MV when the current was under 250 mA[1,2]. The beam loading effect has been investigated by many scientists since Robinson first published his work in 1964 [3-5]. It is common to raise the current limit by increasing the total cavity voltage which is inapplicable in SSRF. Ignition happens frequently when the total cavity voltage is raised from 4.8 MV to 5.4 MV. An alternative way is adopting LLRF feedback. By decreasing the resistance seen by beam, direct feedback loop can help improve current limit [6]. The prototype of the feedback loop is based on the digital LLRF (DLLRF) system used in SSRF storage ring.

RF SYSTEM AND BEAM LOADING

Three RF stations supply necessary power for electron beam. Every RF station controlled individually by its own LLRF system have one cavity and one klystron. The general layout of the RF system in SSRF storage ring is shown in Fig. 1.

The interaction between beam and cavity is always simplified as RLC model [4]. The vector relationship of cavity voltage and beam current which is shown in Fig. 2 indicates the equilibrium status where I_b (I_g) represents beam current (power source) component at RF frequency, V_b (V_g) is the voltage induced by I_b (I_g), V_c is the total voltage seen by beam, φ_s is accelerating phase, φ_z is detuning phase and φ_L is beam loading phase.

Fundamental storage ring parameters of RF system were listed in Table 1.

The basic equations of the RF system parameters and vector diagram are:

$$\tan\varphi_z = 2Q_e \frac{\Delta\omega}{\omega_{rf}}$$

$$R_L = \frac{1}{2} \frac{r}{Q} \times Q_e$$

$$\vec{V}_c = (\vec{I}_b + \vec{I}_g) \times R_L \cos\varphi_z e^{-j\varphi_z}$$

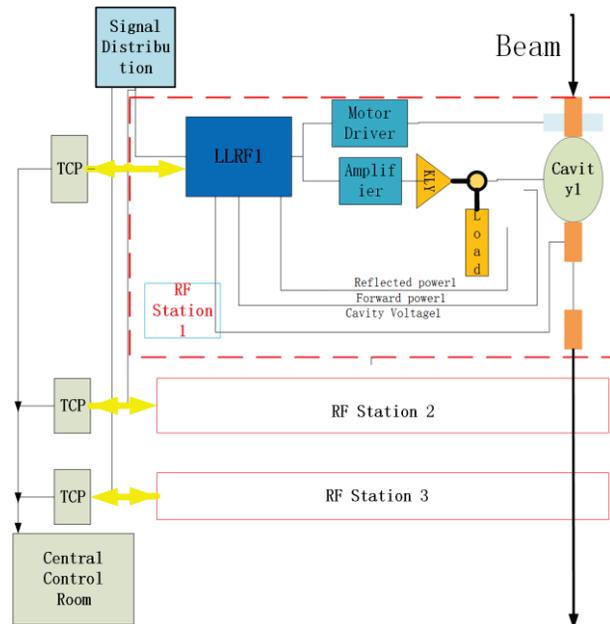


Figure 1: General layout of RF system in the storage ring of SSRF.

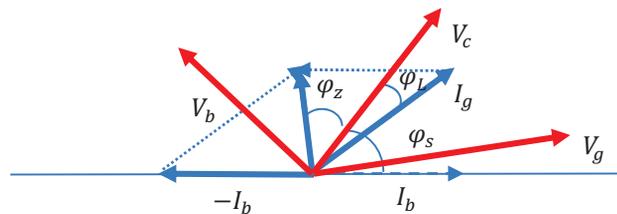


Figure 2: Vector diagram of beam cavity interaction.

It was indicated by Robinson that there will be lack of restoring force for the accelerating phase shift when the beam current is high enough. The critical condition is:

$$\varphi_L + \varphi_z = \varphi_s$$

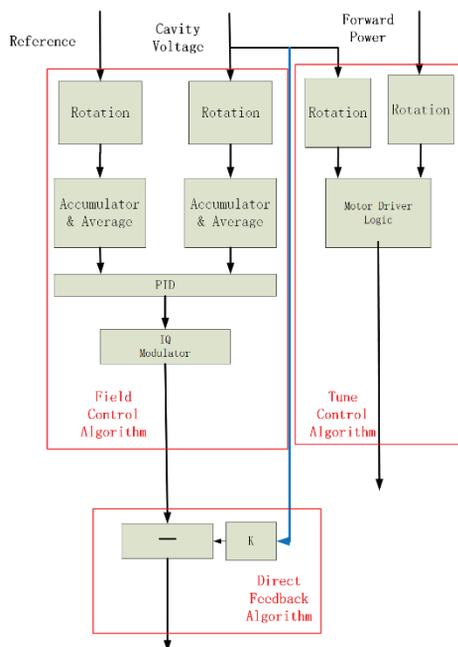


Figure 5: Abstract feedback loop.

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